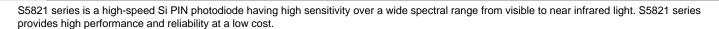
Si PIN photodiode **\$5821 series**

High performance, high reliability Si PIN photodiodes





- High-speed response
- Wide spectral response
- Low dark current
- Low terminal capacitance

Applications

- Optical switch
- Automobile optical sensor
- General photometry

■ General ratings / Absolute maximum ratings

Concrainatings / Absolute maximum ratings											
Type No.	Dimensional outline/ Window material *	Package	Active area size	Effective active area	Absolute maximum ratings						
					Reverse	Power	Operating	Storage			
					voltage	dissipation temperature temperature		temperature			
					VR Max.	P	Topr	Tstg			
		(mm)	(mm)	(mm²)	(V)	(mW)	(°C)	(°C)			
S5821	①/K		φ1.2	1.1	20	50	-40 to +100	-55 to +125			
S5821-01	②/L	TO-18									
S5821-02	3/K										
S5821-03	4)/L										

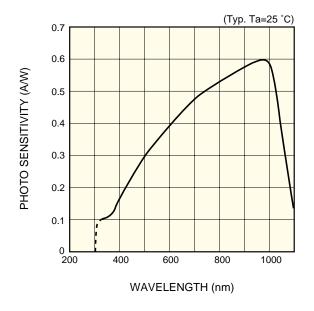
■ Electrical and optical characteristics (Typ. Ta=25 °C, unless otherwise noted)

Type No.	Spectral response range λ (nm)	Peak sensitivity wavelength			sensitivity S A/W)		Short circuit current	curi	ark rent	Temp. coefficient of ID	Cut-off frequency fc	Terminal capacitance	NEP VR=10 V
		λp (nm)		660 nm	780 nm	830 nm	lsc 100 lx (µA)	(n	10 V A) Max	TCID (times/°C)	VR=10 V (MHz)	VR=10 V f=1 MHz (pF)	λ = λ p (W/Hz ^{1/2})
S5821	(11111)	(11111)					1.1	τyp.	IVIAA.	(times/ C)	(1011 12)	(μι)	(۷۷/112)
S5821-01	320 to 1100	960	0.6	0.45	0.52	0.55	12 1.1 12	0.05	2	1.15	25	3	6.7 × 10 ⁻¹⁵

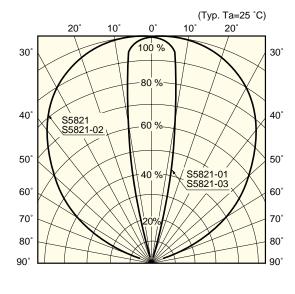
^{*} Window material K: borosilicate glass, L: lens type borosilicate glass



■ Spectral response



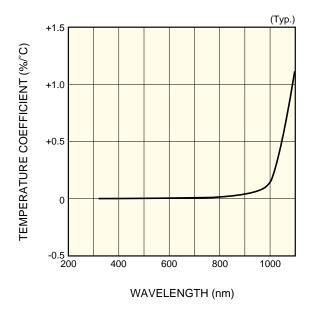
■ Directivity



RELATIVE SENSITIVITY

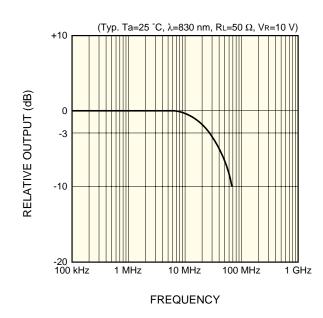
KPINB0091FA

■ Photo sensitivity temperature characteristic



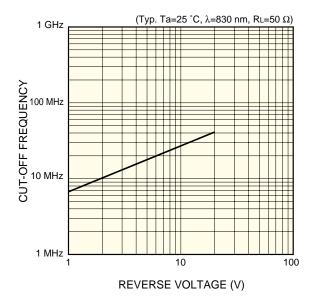
■ Frequency response

KPINB0151EA

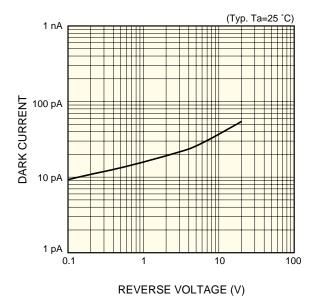


KPINB0152EA KPINB0153EA

■ Cut-off frequency vs. reverse voltage

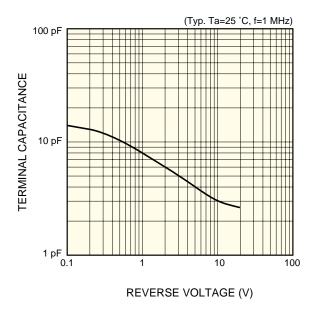


■ Dark current vs. reverse voltage



KPINB0154EA KPINB0155EA

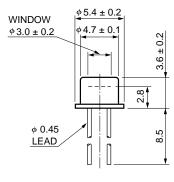
■ Terminal capacitance vs. reverse voltage



KPINB0156EA

■ Dimensional outline (unit: mm)

① S5821

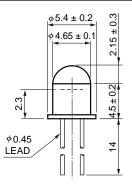


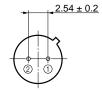




KPINA0074EB

② S5821-01

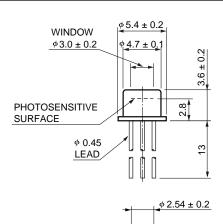






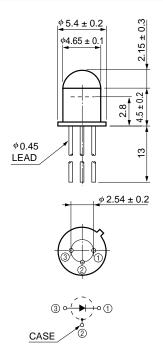
KPINA0075EA

③ S5821-02





4 S5821-03



KPINA0022EB

KPINA0046EA

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